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INFORMATION DISCLOSURE										9/832,867		
						Filing Date				April 12, 2001		
SA	TEM	ENT B	Y API	PLIC	ANT	First Named Inventor			Shunpei YAMAZAKI et al.			
003)	(use as many sheets as necessary)					Group Art Unit			2822			
						Examiner Name			Monica Lewis			
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	filed 12/12/2000 entitled "Semiconductor Device and Manufacturing Method Thereof"									
Examiner	Date									
Signature	Considered									

Specification, drawings, and abstract of U.S. Patent Application Serial No. 09/454,146 filed 12/03/1999 entitled "Semiconductor Device and Method of Fabricating the Same"

Specification, drawings, and abstract of U.S. Patent Application Serial No. 09/735,204

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